

Parameter	Symbol	Rating	Units	
Load Voltage	VL	60	V	
Load Current	lι	1.1	Α	
On-Resistance	Ron	0.13	Ω	
I/O Breakdown Voltage	V/ıo	2500	Vrms	





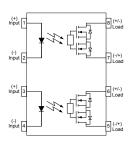




E534710



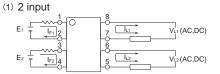
SOP-8

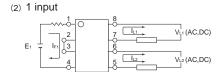


1,3. LED Anode

2,4. LED Cathode 5,6. Drain (MOS FET)

7,8. Drain (MOS FET)





APSEMI PhotoRelays

APSEMI Photorelays are the most reliable, technically advanced logic-to-power interface devices. Their basic function is to take a low current signal from a microprocessor to control the switching of both AC and DC loads, while providing an isolation barrier between logic and power. While this function is common to all relays, Photorelays provide distinct advantages over their mechanical counterparts including:

- Long life (No limit on mechanical and electrical
- lifetime)Bounce-free switching
- · Higher speed and high frequency switching
- Higher sensitivity (less power consumption)
- Immunity to EMI or RFI

- No have voltaic arc, bounce, and noise More
- resistant to vibration and impact AC or DC load
- switching
- Small package size

Applications

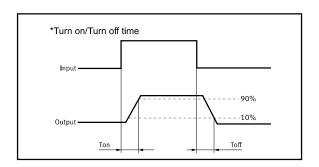
These advantages make APSEI Photorelays the ideal choice for:

- Telecom/Datacom switching
- Multiplexers
- Meter reading systems
- Data acquisition
- Medical equipment
- Battery monitoring
- I/O Sub-Systems

- Robotics
- Aerospace
- Home/Safety security systems
- Process Control
- Energy Management
- Reed Relay EMR Replacement
- Programmable Controllers

TPYES

Output Rating		Doolsome	Part No.	Packing Overtity		
Category	Load Voltage	Load Current	Package	Part No.	Packing Quantity	
AC/DC	60V	1.1A	SOP-8	APW212G1S	2000pcs /reel	





Absolute Maximum Ratings (Ta = 25°C)

	Item	Symbol	Value	Units	Note
	Continuous LED Current	lF	50	mA	
Input	Peak LED Current	I FP	1000	mA	f=100Hz, duty=1%
·	LED Reverse Voltage	VR	5	V	
	Input Power Dissipation	P _{In}	75	mW	
Output	Load Voltage	V∟	60	V(AC peak or DC)	
	Load Current	l.	1.1	Α	
	Peak Load Current	Peak	3.0	Α	100ms (1 pulse)
	Output Power Dissipation	Pout	380	mW	
Total Power	Dissipation	P⊤	450	mW	
I/O Breakdov	wn Vo l tage	V _{I/O}	2500	Vrms	RH=60%, 1min
Operating Te	emperature	Торг	-40 to 85	°C	
Storage Tem	perature	T _{stg}	-40 to 100	°C	
Pin Soldering	g Temperature	T _{sol}	260	°C	10 sec max.

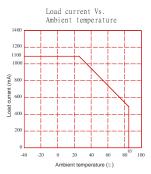
Electrical Characteristics (Ta = 25°C)

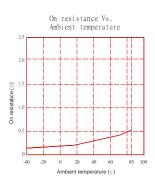
	Item	Symbol	MIN.	TYP.	MAX.	Units	Conditions
	LED Forward Voltage	VF		1.2	1.4	V	I⊧=10mA
	Operation LED Current	Fon		0.5	2.0	mA	
Input	Recovery LED Current	Foff		0.35	0.5	mA	
	Recovery LED Voltage	V_{Foff}	0.7			V	
							I⊧=5mA,I∟=100mA,
	On-Resistance	Ron		0.13	0.5	Ω	Time to flow is within 1 sec.
Output	Off-State Leakage	Leak	0.01	0.02	0.1	uA	V _∟ =Rating
	Current		0.01	0.02	0.1		ŭ
	Output Capacitance	C_{out}		185		pF	V∟=0, f=1MHz
Transmis	Turn-On Time	Ton		0.2	1.5	ms	I⊧=5mA, I∟=100mA,
sion	Turn-Off Time	T_{off}		0.6	0.8	ms	
Coupled	I/O Isolation Resistance	R _{I/O}	10 ¹⁰			Ω	DC500V
Coupled	I/O Capacitance	Ci/o		0.8	1.5	pF	f=1MHz

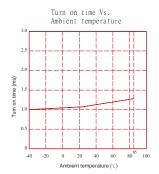
Please obey the following conditions to ensure proper device operation and resetting. Input LED current (Recommended value): IF ≥5mA and ≤30mA

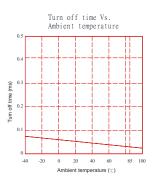


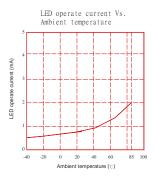
Engineering Data

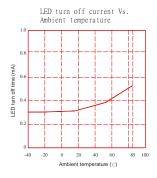


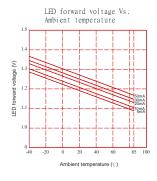


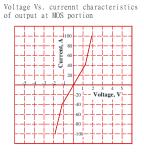


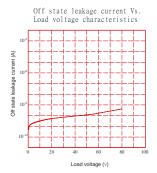


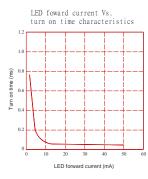


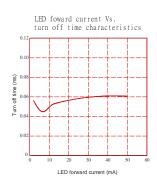


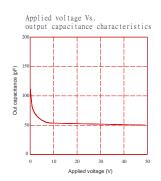








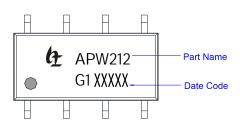






Dimensions and SOP-8 Package Unit: mm

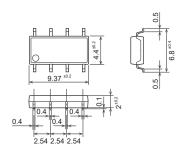
Marking



Lable



Surface mount terminal type

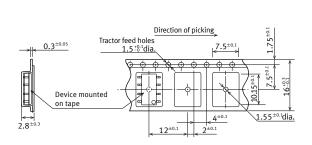


Recommended mounting pad (Top view)

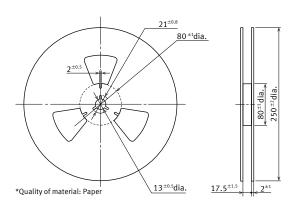


Tape dimensions (tape reel)

Tape dimensions (Unit: mm)



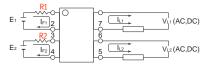
Dimensions of paper tape reel (Unit: mm)





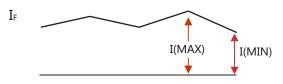
Using Methods

Examples of resistance value to control LED forward current (IF=5mA)



E1 E2	R1 R2(Approx)
3.3V	300 Ω
5.0V	600 Ω
12V	1.9KΩ
24V	4.1K Ω

LED forward current must be more than 5mA, at I(MIN), and less than 30mA, at I(MAX).



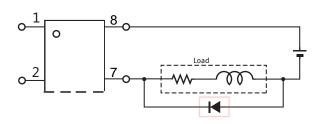
Recommended Operating Conditions

Please obey the following conditions to ensure proper device operation and resetting. Input LED current (Recommended value):

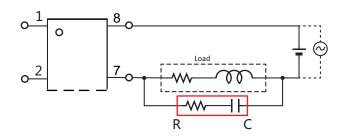
Characteristic	Symbol	Min	Тур.	Max	Unit
Forward current	lF	5.0	7.0	30	mA

Protection Circuit

Clamp diode is connected in parallel with the load. Absorb capacity with external diode.



CR Snubber is connected in parallel with the load. Absorb capacity with buffer capacity.



When adding diodes, buffer circuits (C-R), and other protections, they need to be installed near the MOS RELAY to be effective. Adding protection elements may result in a slow reset time, so adjust them according to the actual situation before use.

Note: When developing designs using this product, perform the expected performance of the equipment under the operating conditions recommended by the guidelines in this document. Continuous use under heavy loads (including, but not limited to, the application of high temperatures/current/voltage and significant changes in temperature, etc.) may result in deterioration of the reliability of this product.



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